BT136B series D

GENERAL DESCRIPTION

Glass passivated, sensitive gate triacs in a plastic envelope suitable for surface mounting, intended for use in general purpose bidirectional switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

DESCRIPTION

main terminal 1

main terminal 2

main terminal 2

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	UNIT
V _{drm} I _{t(rms)} I _{tsm}	BT136B- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	500D 500 4 25	600D 600 4 25	V A A

PIN CONFIGURATION

-D-

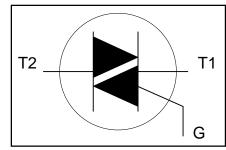
2

3

1

-

SYMBOL



LIMITING VALUES

gate

PINNING - SOT404

PIN

1

2

3

mb

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	UNIT	
V _{drm}	Repetitive peak off-state voltages		-	-500 500 ¹	-600 600 ¹	v
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 107$ °C full sine wave; $T_j = 25$ °C prior to surge	-	4		A
		t = 20 ms t = 16.7 ms	-		5 7	A
l²t dI⊤/dt	I ² t for fusing Repetitive rate of rise of on-state current after	t = 10.7 ms t = 10 ms $I_{TM} = 6 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-	3	.1	A A ² s
	triggering	T2+ G+ T2+ G- T2- G- T2- G+		5 5	0 0 0 0	A/μs A/μs A/μs A/μs
I _{GM} V _{GM} P _{GM} P	Peak gate current Peak gate voltage Peak gate power Average gate power	over any 20 ms period				A V W W
$ \begin{array}{c} P_{G(AV)} \\ T_{stg} \\ T_{j} \end{array} $	Storage temperature Operating junction temperature		-40 -	15	.5 50 25	Û Û

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 3 $A/\mu s$.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb} R _{th j-a}	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle minimum footprint, FR4 board	- - -	- - 55	3.0 3.7 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

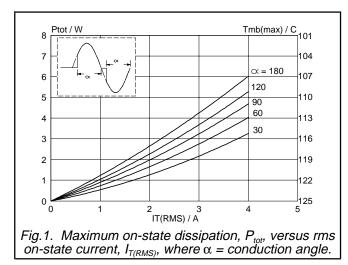
SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
01			T2+ G+	-	2.0	5	mA
			T2+ G-	-	2.5	5	mA
			T2- G-	-	2.5	5	mA
			T2- G+	-	5.0	10	mA
	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$					
			T2+ G+	-	1.6	10	mA
			T2+ G-	-	4.5	15	mA
			T2- G-	-	1.2	10	mA
			T2- G+	-	2.2	15	mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$		-	1.2	10	mA
I _H V _T V _{GT}	On-state voltage	$I_T = 5 A$		-	1.4	1.70	V
V _{GT}	Gate trigger voltage	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
		$ V_{D} = 400 V; I_{T} = 0.1 A; T_{i} = 125$ °	C	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{D}^{D} = 400 \text{ V}; I_{T} = 0.1 \text{ A}; T_{j} = 125 ^{\circ}$ $V_{D} = V_{DRM(max)}; T_{j} = 125 ^{\circ}C$		-	0.1	0.5	mA

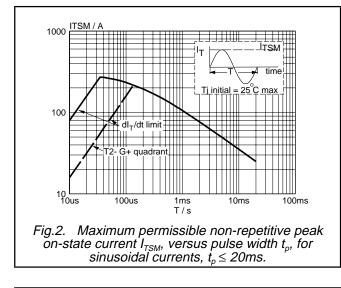
DYNAMIC CHARACTERISTICS

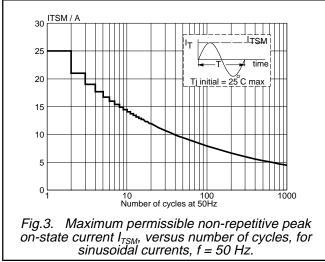
 $T_i = 25$ °C unless otherwise stated

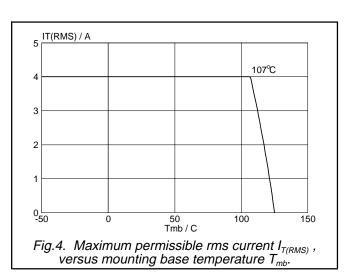
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	-	5	-	V/µs
t _{gt}		exponential waveform; $R_{GK} = 1 \ k\Omega$ $I_{TM} = 6 \ A$; $V_D = V_{DRM(max)}$; $I_G = 0.1 \ A$; $dI_G/dt = 5 \ A/\mu s$	-	2	-	μs

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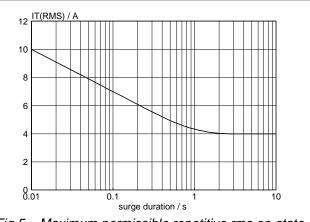
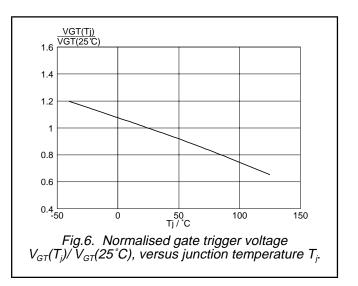
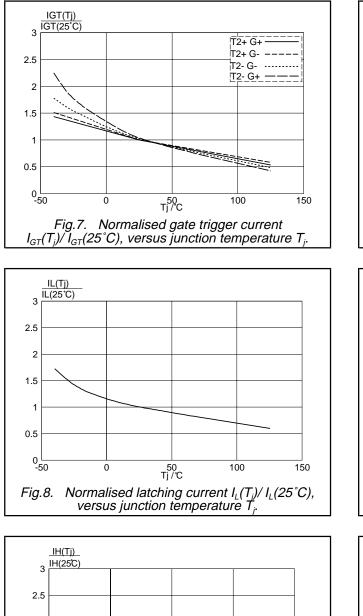
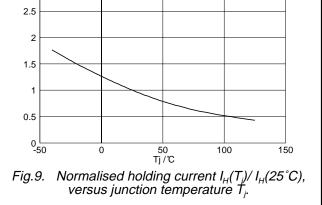


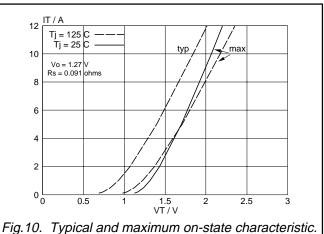
Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 107^{\circ}C$.

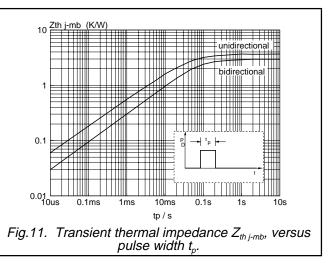


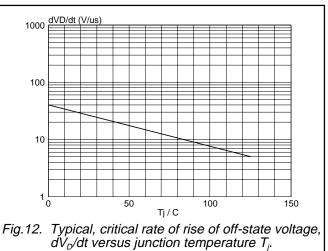
BT136B series D





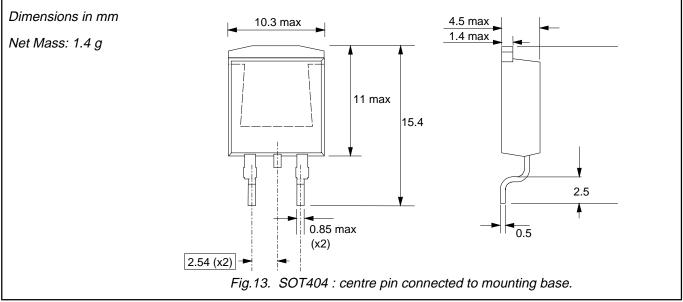






BT136B series D

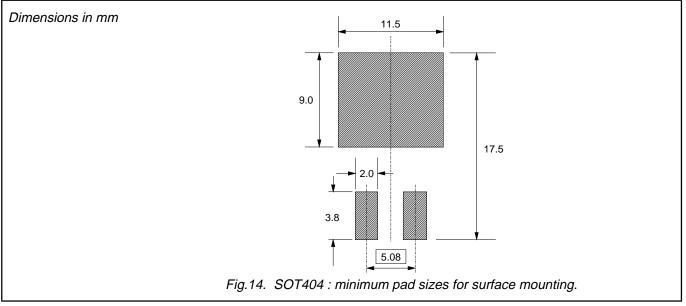
MECHANICAL DATA



Notes

1. Epoxy meets UL94 V0 at 1/8".

MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

Triacs	BT136B series D
logic level	

DEFINITIONS

Data sheet status					
Objective specification This data sheet contains target or goal specifications for product development.					
Preliminary specification	Preliminary specification This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values	Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.					
Application information					
Where application information is given, it is advisory and does not form part of the specification.					

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